

High Temperature Resistant Transparent Conductive Films for Photoelectrochemical Devices Based on W/Ag Composite Nanonetworks

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Supplementary Data

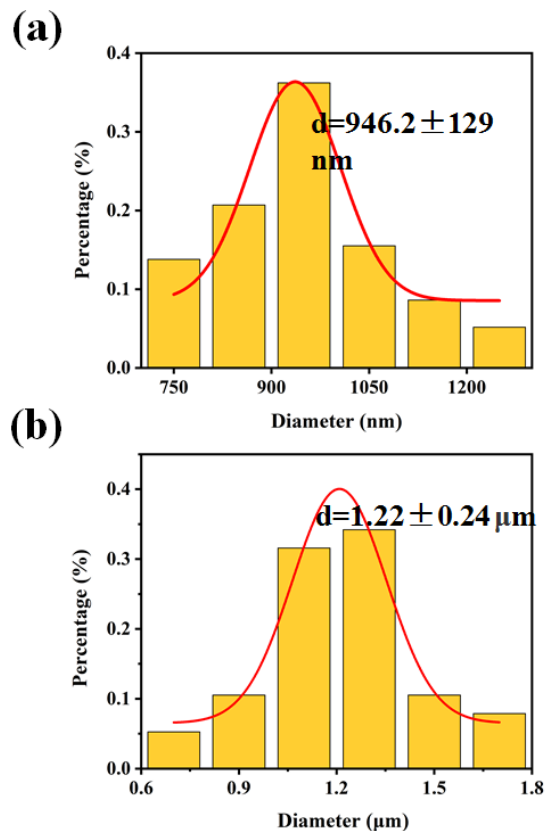


Figure S1. Diameter statistics of (a) Ag nanowires and (b) W/Ag composite

nanowires.

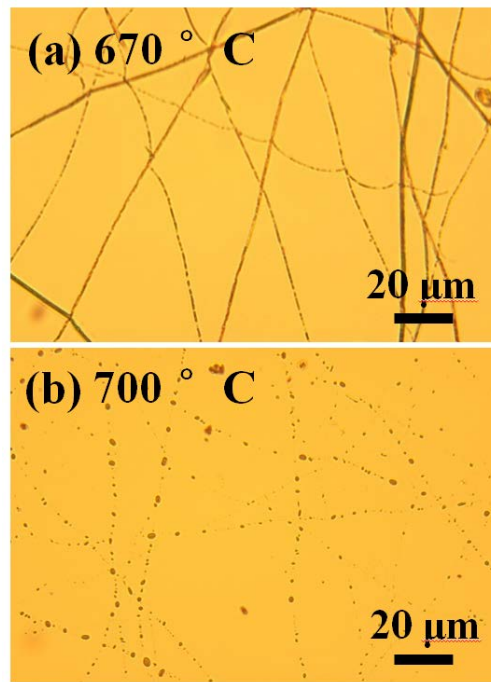


Figure S2. The melting state of W nanowires at different temperatures.